

## Initial Design

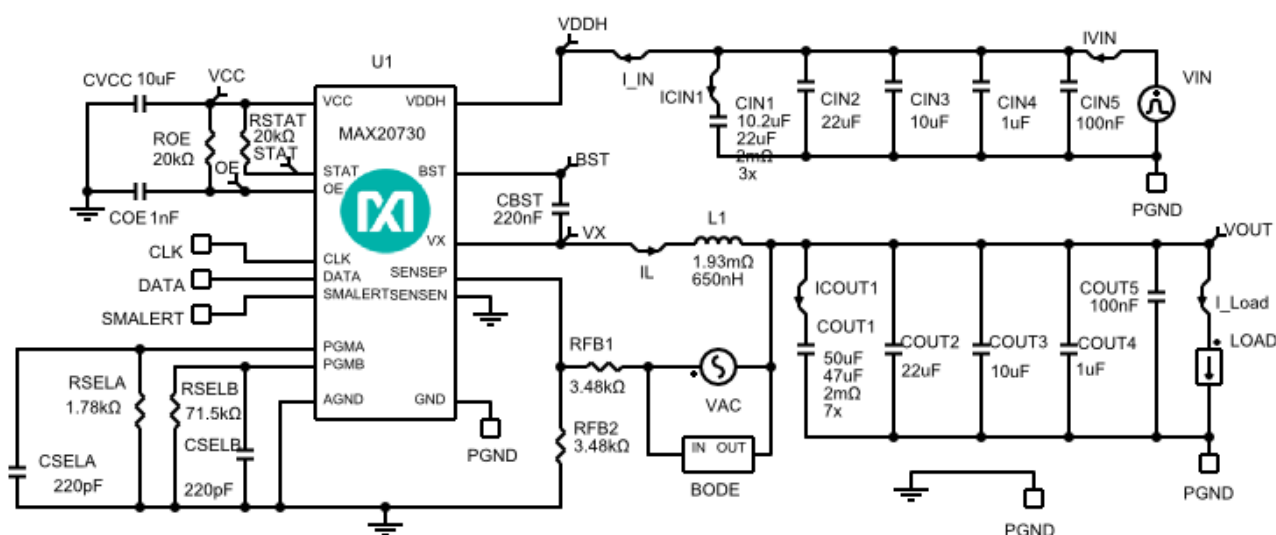
1.0

**Design Requirements**

Parameter	Value
Minimum Input Voltage	10V
Maximum Input Voltage	14V
Nominal Input Voltage	12V
Input Voltage Ripple	1%
Output Voltage	1.8V
Output Current	15A
Output Voltage Ripple	1%
Load Step Start Current	7.5A
Load Step Current	15A
Load Step Edge Rate	5A/us
Output Voltage Load Step Over/Undershoot	5%
Performance Priority	Balance Efficiency and Size
BOM Priority	Cost
Ambient Temperature	25°C
Inductor Current Ratio (LIR)	0.3
PMBus Address	1010000
Parameter Programming Method	Boot Components
Vboot Reference Voltage	0.8984 V
PMBus Reference Voltage	0.7V
Switching Frequency	600 KHz
Rgain	1.8 mOhm
Soft Start Ramp Time	3 ms
STAT Blanking Time	125 us

Parameter	Value
OCP Threshold	Setting 1
Overtemperature Protection Threshold	150 °C

## Schematic



Over-temperature Protection (OTP) and Over-current Protection (OCP) are not modeled in EE-Sim.

Increasing COUT1 will decrease the loop bandwidth and increase the phase margin. Decreasing COUT1 will have the opposite effect.

This note only applies to the online EE-Sim Design Tool: RSELA, CSELA, RSELB and CSELB are set to the proper values for the design requirements entered. To change any of the chip parameters that these components set, change the design requirements accordingly and create a new design.

## BOM

Ref	Qty	Part Number	Manufacturer	Description
U1	1	<a href="#">MAX20730</a>	Maxim Integrated	4.5V to 16V, Integrated Step-Down Switching Regulator 25A, with PMBus
CBST	1	<a href="#">CC0402KRX5R6BB224</a>	Yageo	Cap Ceramic 0.22uF 10V X5R 10% Pad SMD 0402 85°C T/R
CIN1	3	<a href="#">GRM32ER71E226ME15</a>	Murata	Cap Ceramic 22uF 25V 1210 125C
CIN2	1	<a href="#">CL31A226KOHNNNE</a>	Samsung Electro-Mechanics	Cap Ceramic 22uF 16V X5R 10% Pad SMD 1206 85°C T/R
CIN3	1	<a href="#">GRM21BR61C106KE15L</a>	Murata Manufacturing	Cap Ceramic 10uF 16V X5R 10% Pad SMD 0805 85°C T/R
CIN4	1	<a href="#">EMK105BJ105KV-F</a>	Taiyo Yuden	Cap Ceramic 1uF 16V X5R 10% Pad SMD 0402 85°C T/R

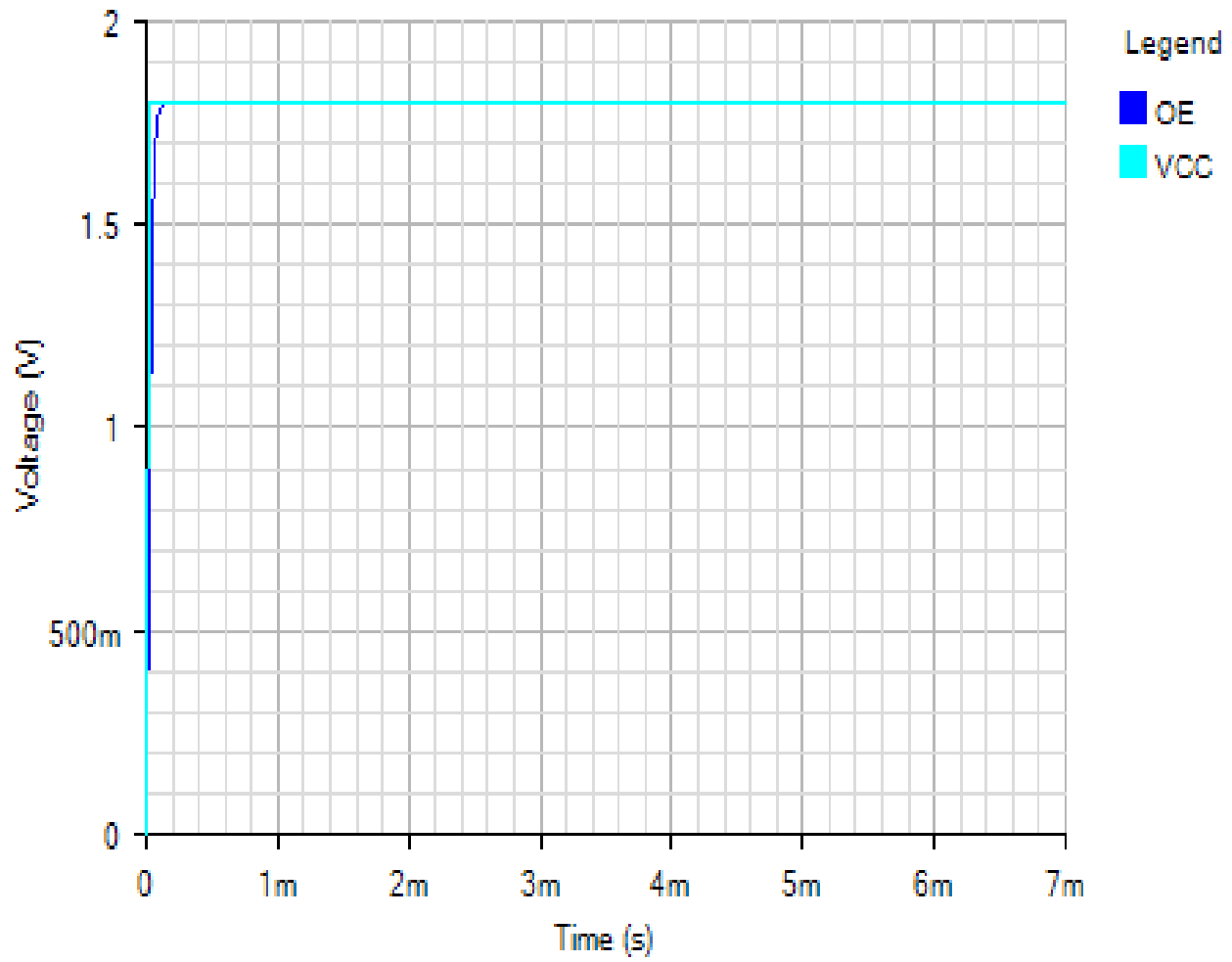
CIN5	1	<a href="#">CC0402KRX7R8BB104</a>	Yageo	Cap Ceramic 0.1uF 25V X7R 10% Pad SMD 0402 125°C T/R
COE	1	<a href="#">CC0402KRX7R8BB102</a>	Yageo	Cap Ceramic 0.001uF 25V X7R 10% Pad SMD 0402 125°C T/R
COUT1	7	<a href="#">GRM32ER71A476ME15L</a>	Murata	Cap Ceramic 47uF 10V X7R 20% SMD 1210 125C Embossed T/R
COUT2	1	<a href="#">JMK212BJ226KG-T</a>	Taiyo Yuden	Cap Ceramic 22uF 6.3V X5R 10% Pad SMD 0805 85°C T/R
COUT3	1	<a href="#">C1608X5R1A106K080AC</a>	TDK	Cap Ceramic 10uF 10V X5R 10% Pad SMD 0603 85°C T/R
COUT4	1	<a href="#">EMK105BJ105KV-F</a>	Taiyo Yuden	Cap Ceramic 1uF 16V X5R 10% Pad SMD 0402 85°C T/R
COUT5	1	<a href="#">CC0402KRX7R8BB104</a>	Yageo	Cap Ceramic 0.1uF 25V X7R 10% Pad SMD 0402 125°C T/R
CSELA	1	<a href="#">C0402C221K4RACTU</a>	KEMET Corporation	Cap Ceramic 220pF 16V X7R 10% Pad SMD 0402 125°C T/R
CSELB	1	<a href="#">C0402C221K4RACTU</a>	KEMET Corporation	Cap Ceramic 220pF 16V X7R 10% Pad SMD 0402 125°C T/R
CVCC	1	<a href="#">NMC0402X5R106K6.3TRPF</a>	NIC Components	Cap Ceramic 10uF 6.3V X5R 10% Pad SMD 0402 85°C T/R
L1	1	<a href="#">XAL7070-651MEB</a>	Coilcraft	Inductor 650nH 20% 1.75mOhm 28.5A Isat 26.5A Irms
RFB1	1	<a href="#">ERJ2RKF3481X</a>	Panasonic	Res Thick Film 0402 3.48K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
RFB2	1	<a href="#">ERJ2RKF3481X</a>	Panasonic	Res Thick Film 0402 3.48K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
ROE	1	<a href="#">ERJ2GEJ203X</a>	Panasonic	Res Thick Film 0402 20K Ohm 5% 0.1W(1/10W) ±200ppm/°C Pad SMD Automotive T/R
RSELA	1	<a href="#">ERJ2RKF1781X</a>	Panasonic	Res Thick Film 0402 1.78K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
RSELB	1	<a href="#">ERJ2RKF7152X</a>	Panasonic	Res Thick Film 0402 71.5K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
RSTAT	1	<a href="#">ERJ2GEJ203X</a>	Panasonic	Res Thick Film 0402 20K Ohm 5% 0.1W(1/10W) ±200ppm/°C Pad SMD Automotive T/R

## Simulation Results

**Start Up - Tue Nov 20 2018 13:54:57**

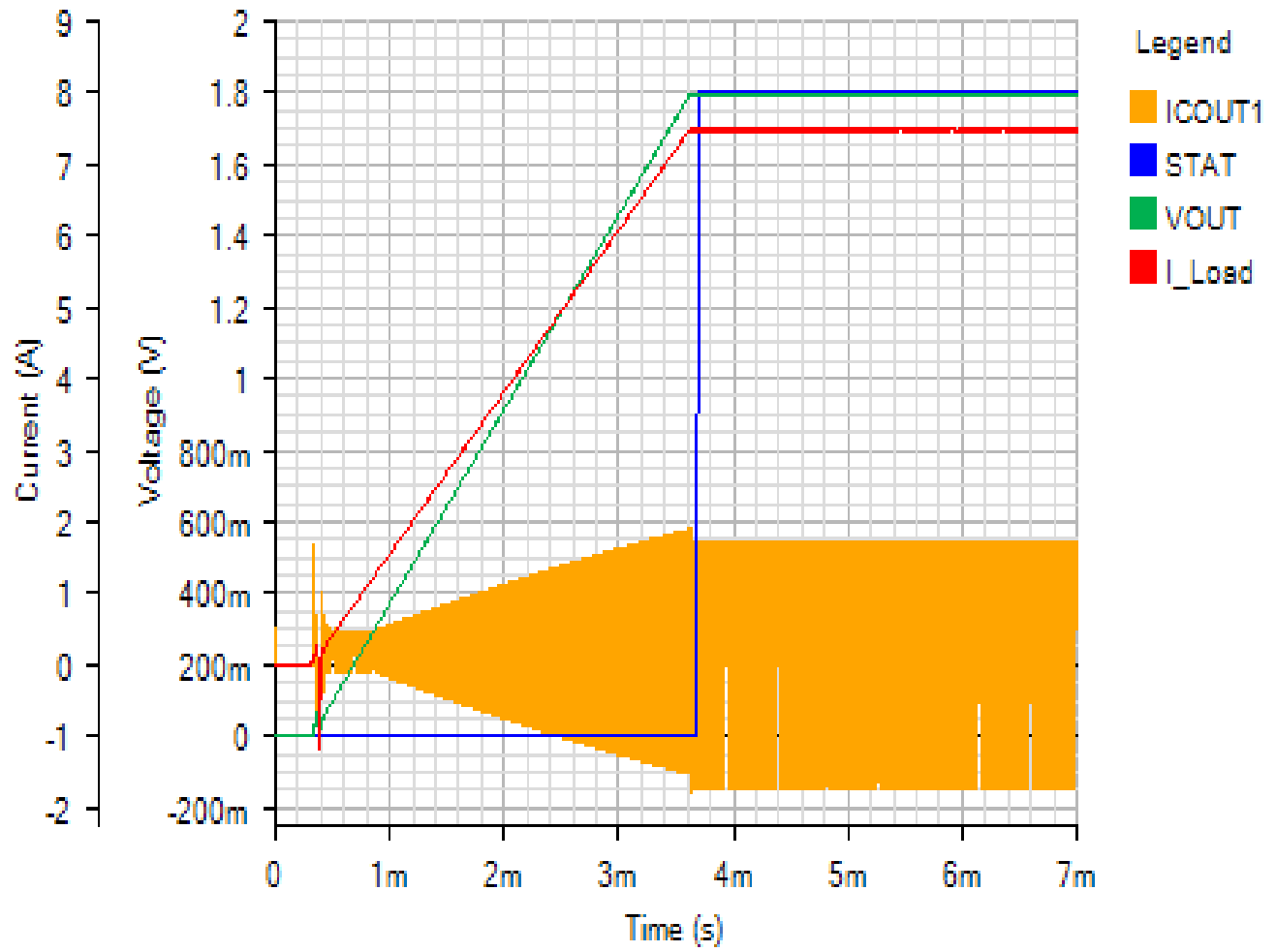
IC

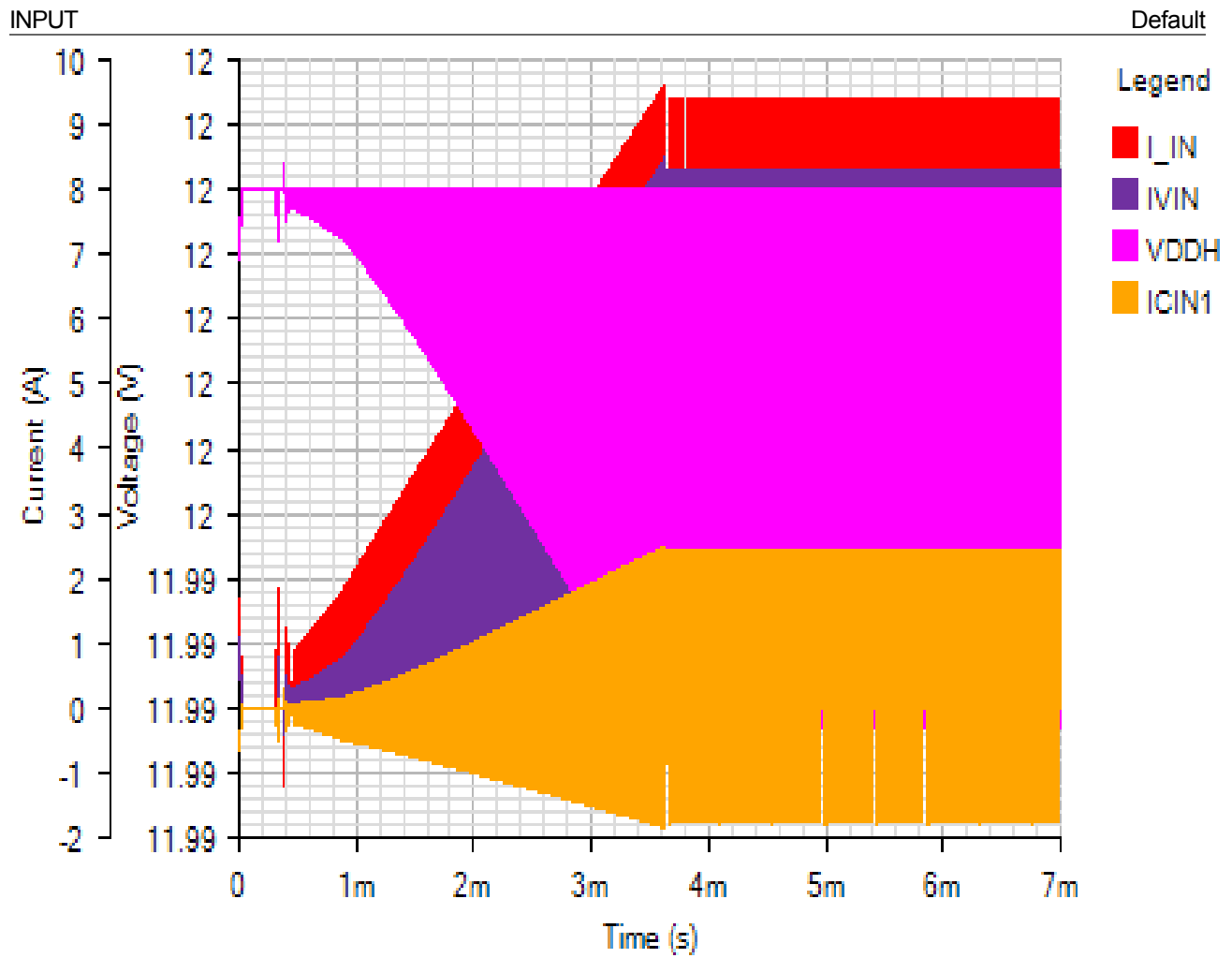
Default



OUTPUT

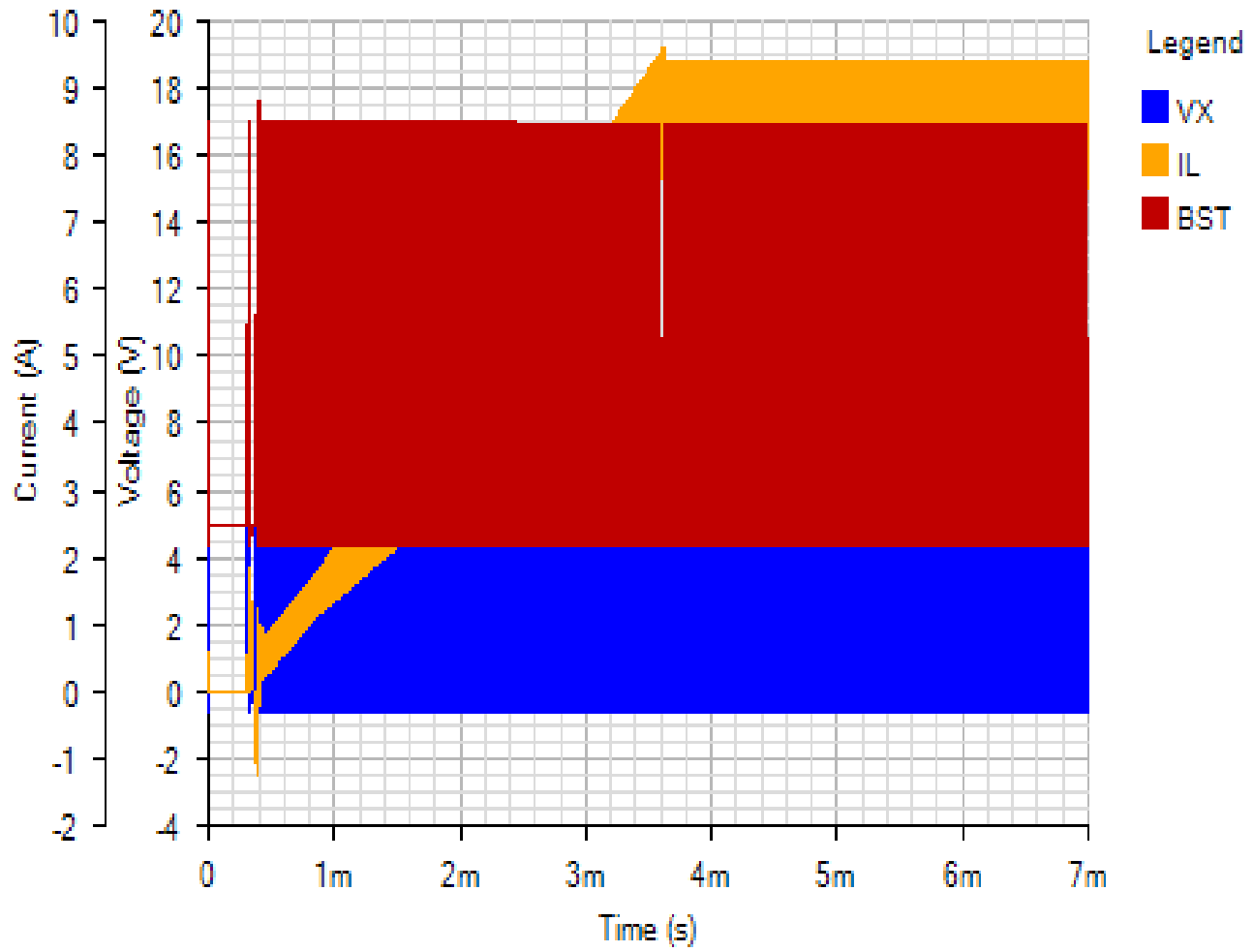
Default





SWITCHING

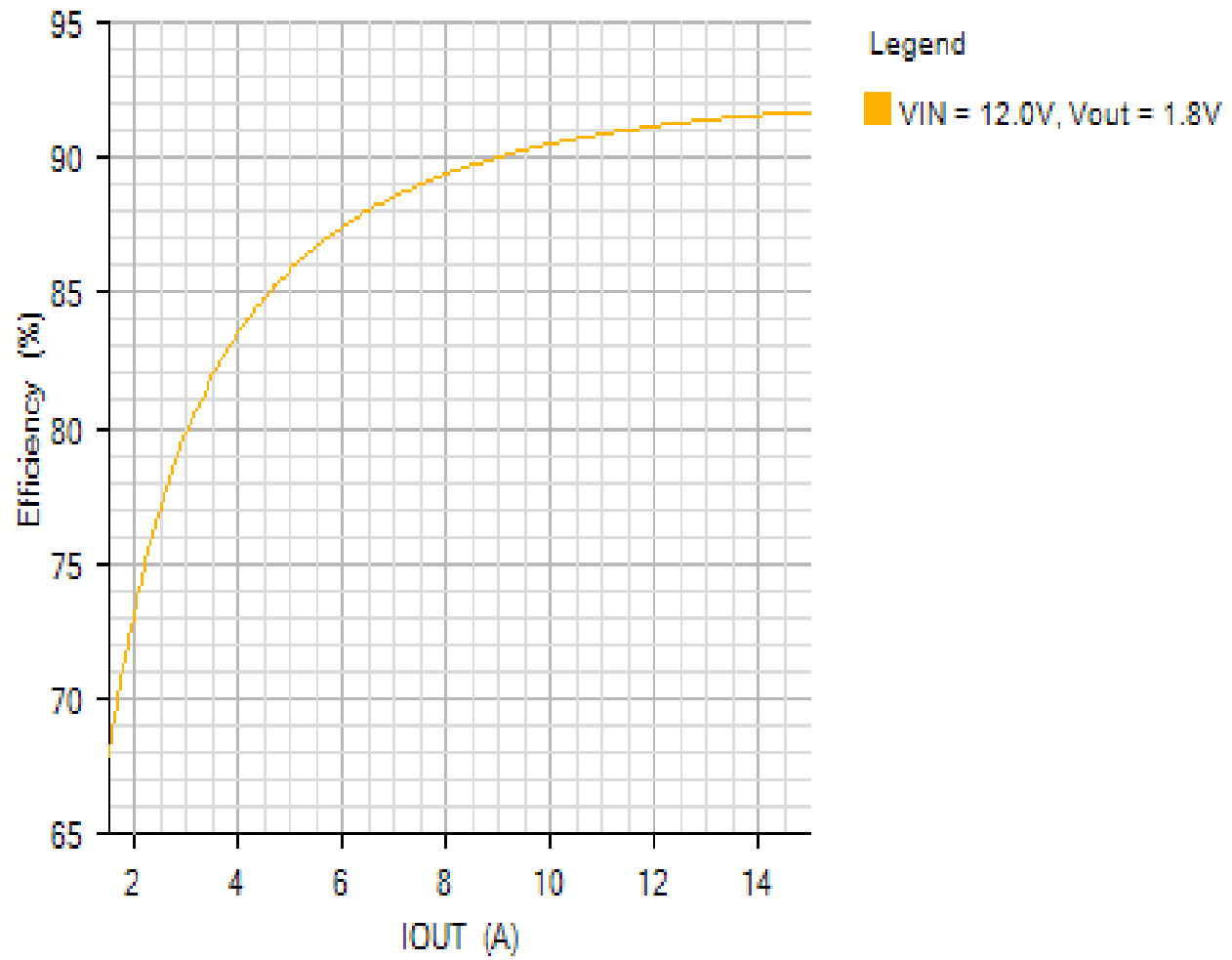
Default



Efficiency - Tue Nov 20 2018 13:54:57

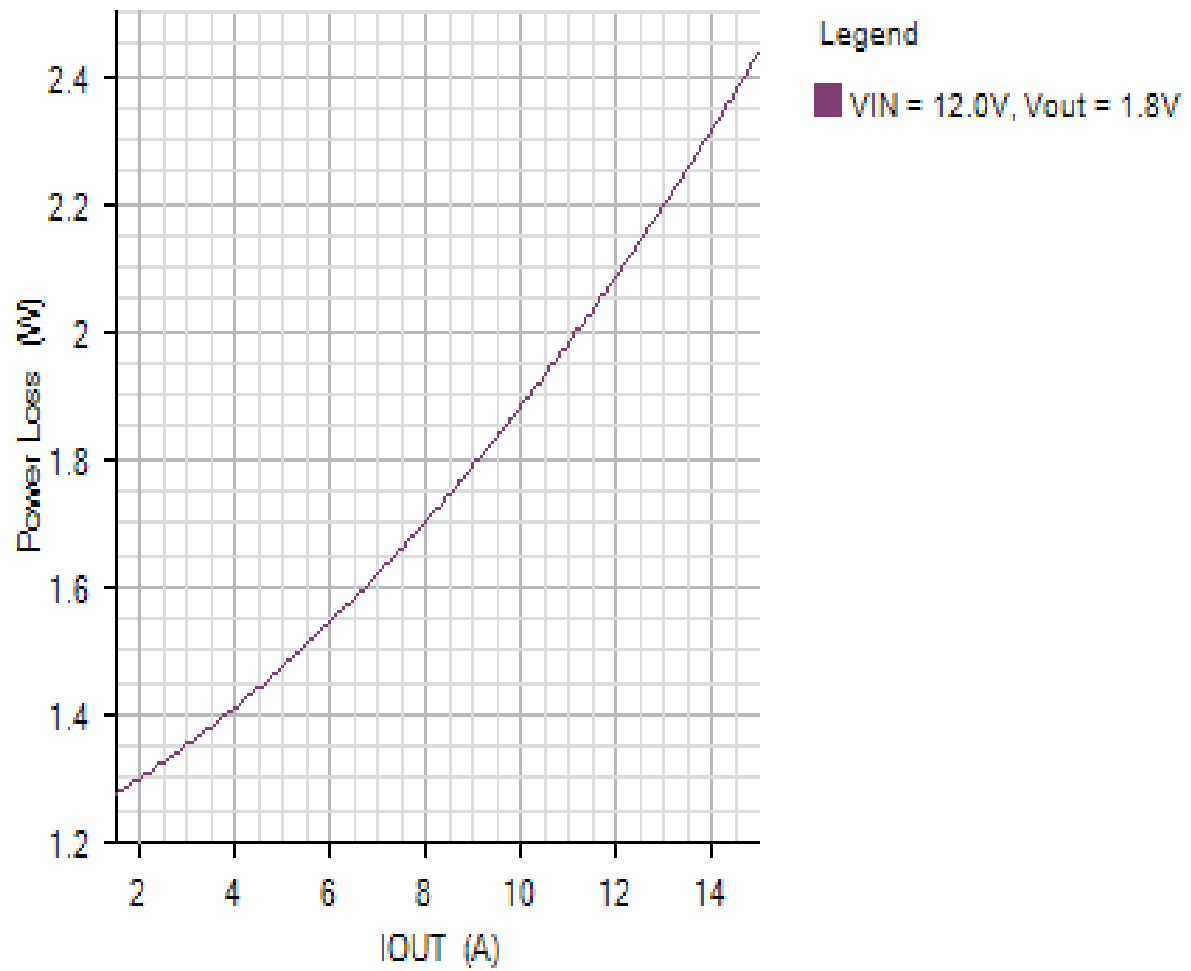
EFFICIENCY\_PLOT

Default



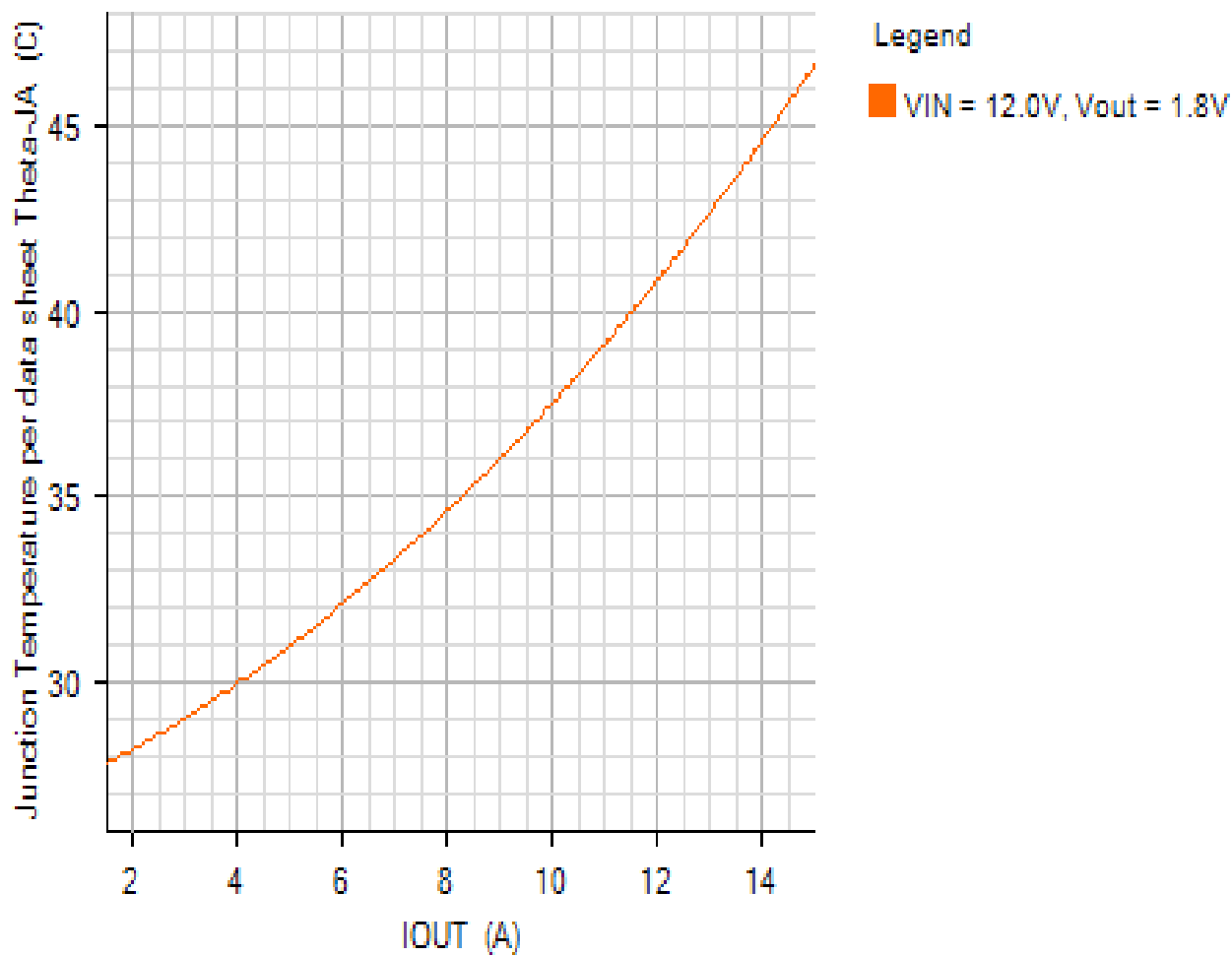
POWER\_LOSS\_PLOT

Default

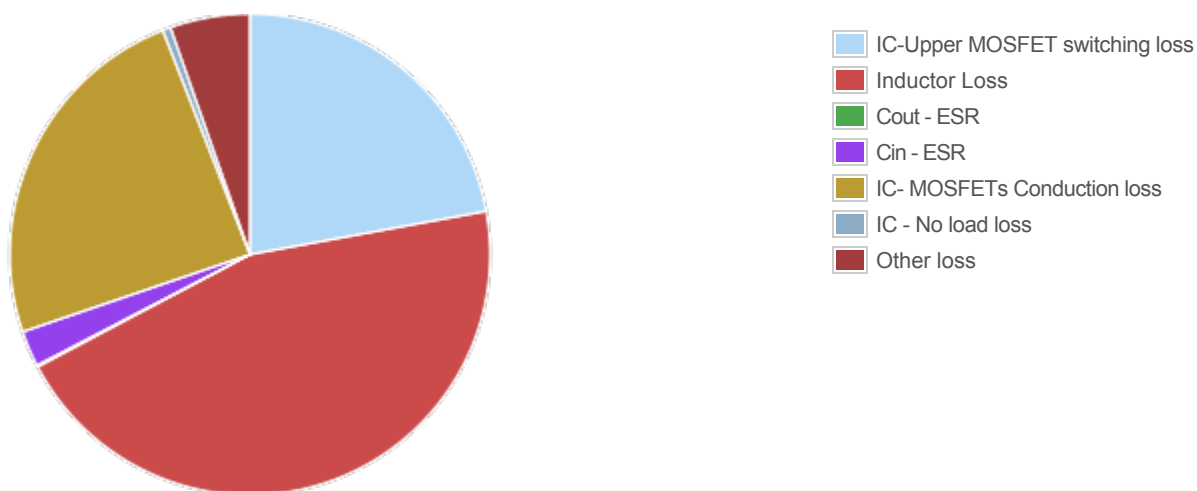


JUNCTION\_TEMPERATURE\_PLOT

Default



Losses



Component

Loss (W)

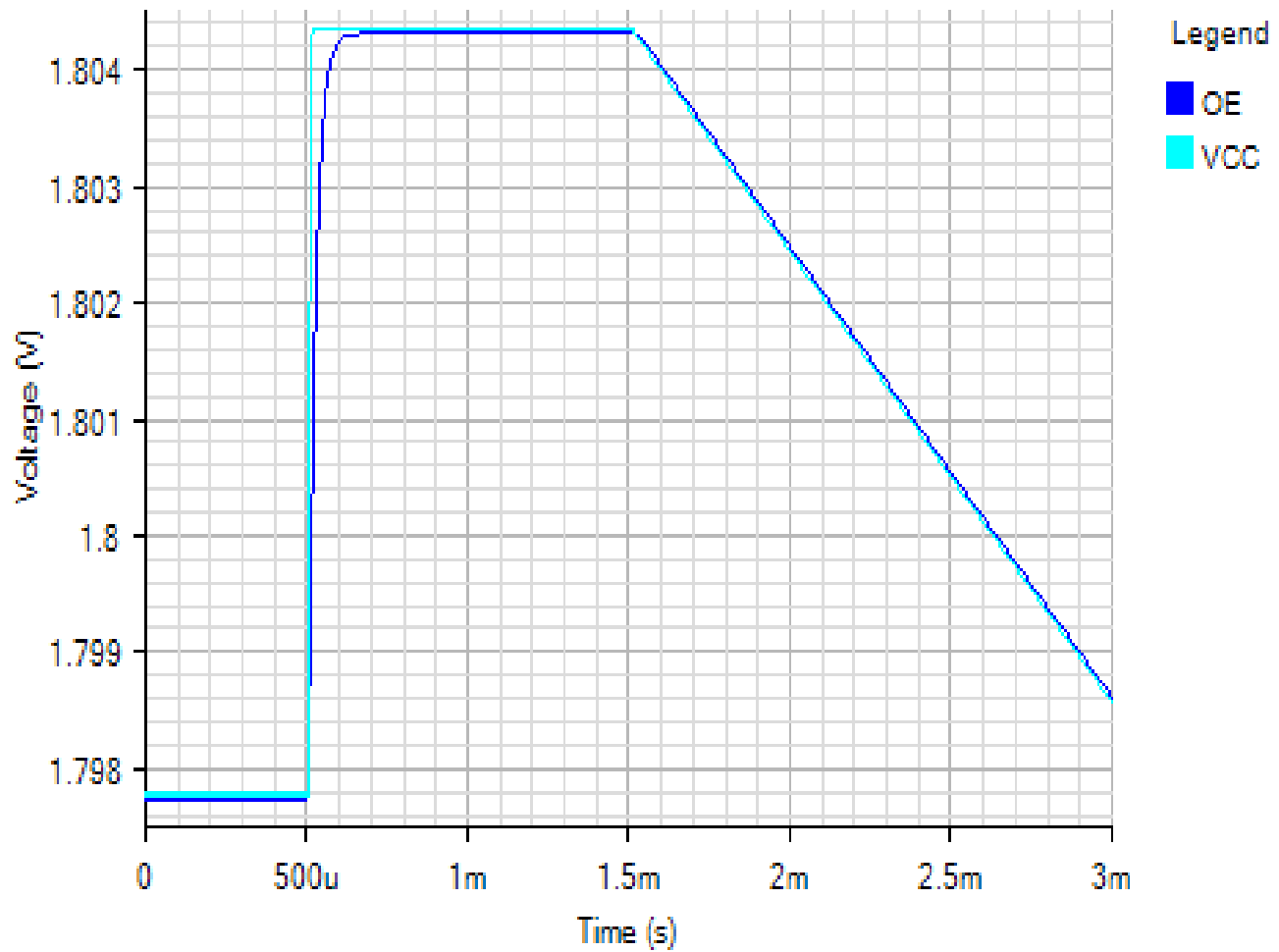
% of total

Component	Loss (W)	% of total
IC-Upper MOSFET switching loss	0.539	22.1
Inductor Loss	1.1	45.1
Cout - ESR	0.0025	0.1
Cin - ESR	0.0589	2.4
IC- MOSFETs Conduction loss	0.592	24.3
IC - No load loss	0.0132	0.5
Other loss	0.131	5.4
Total	2.4366	100

Line Transient - Tue Nov 20 2018 13:54:57

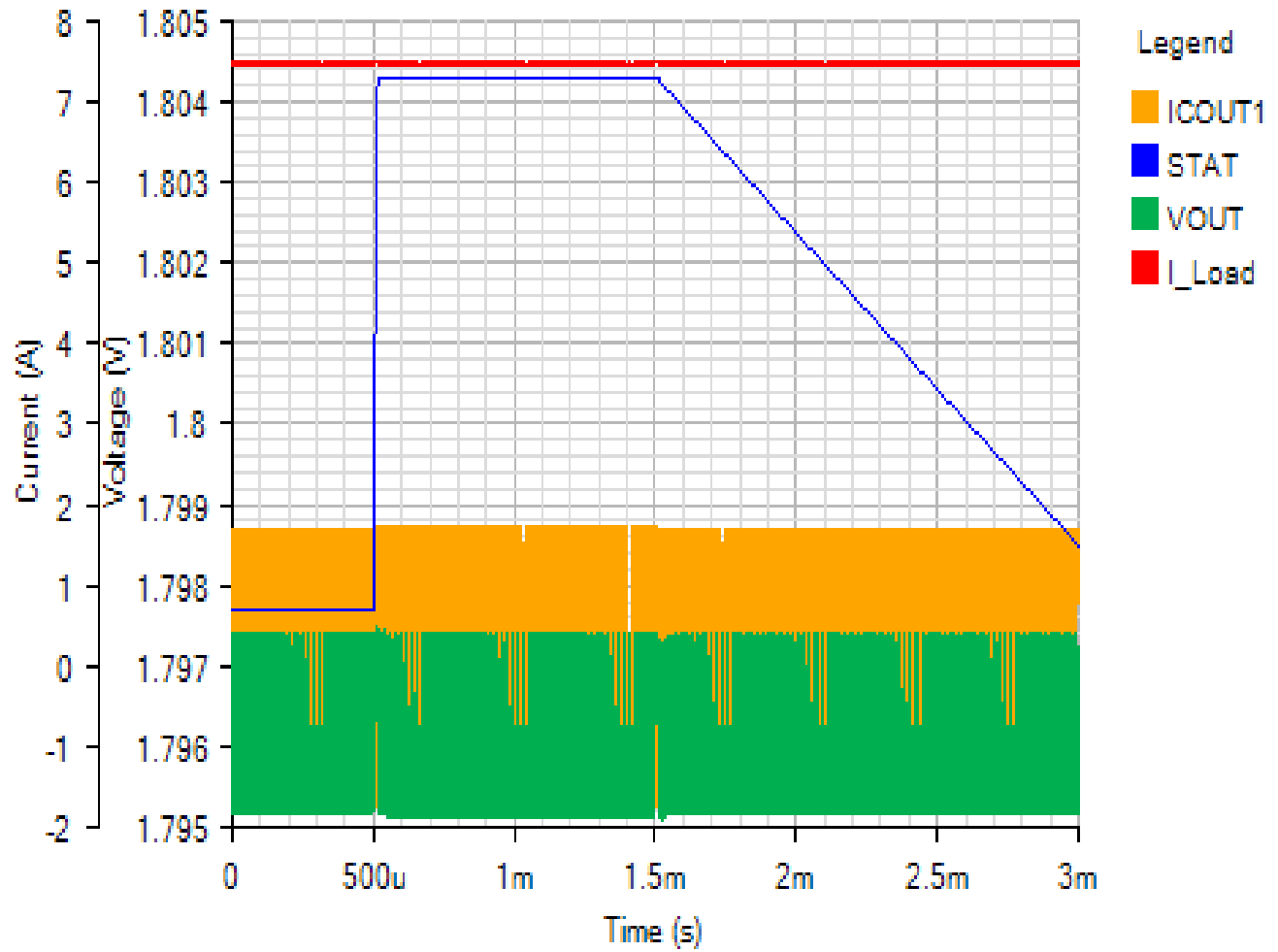
IC

Default



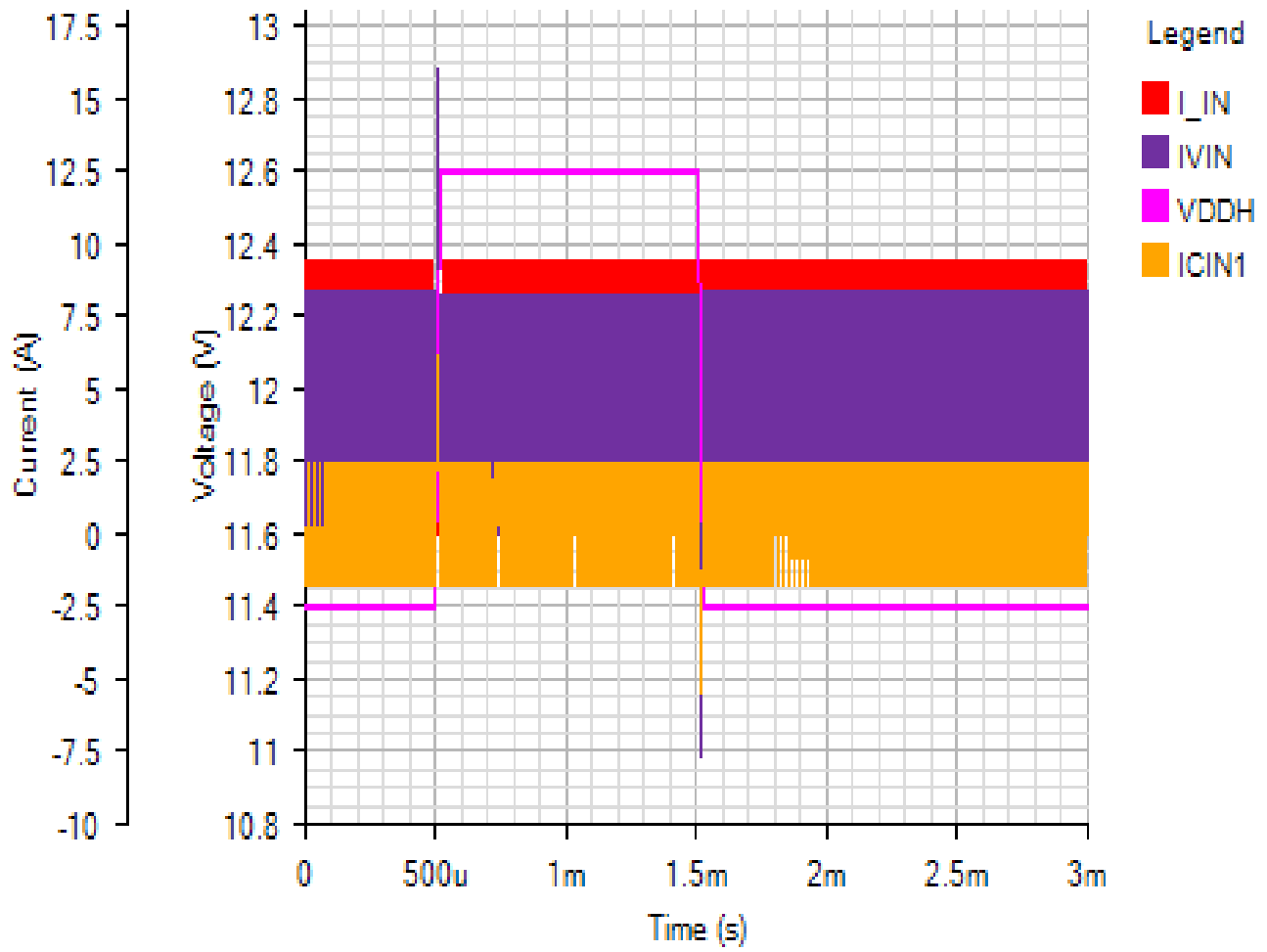
OUTPUT

Default



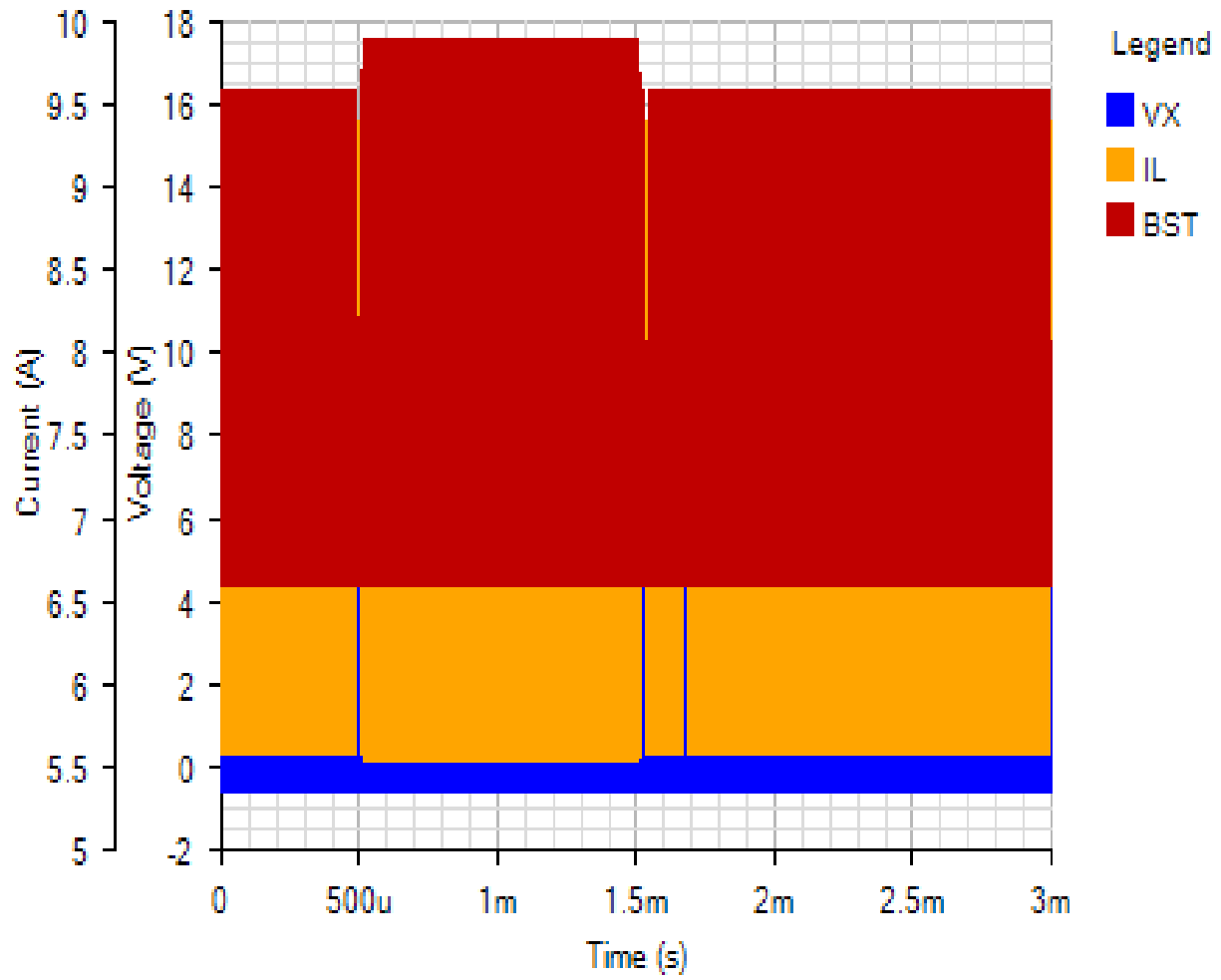
INPUT

Default

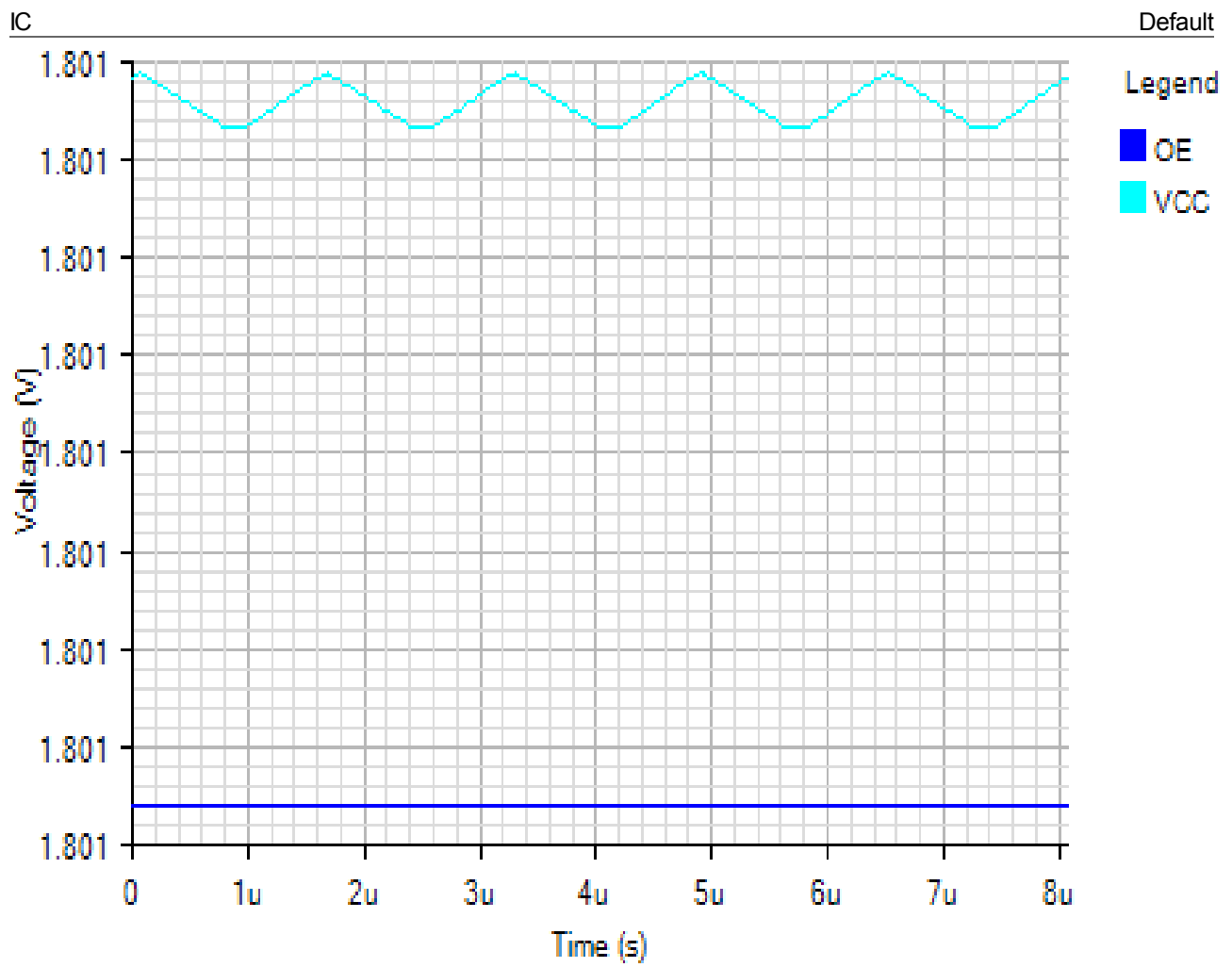


SWITCHING

Default

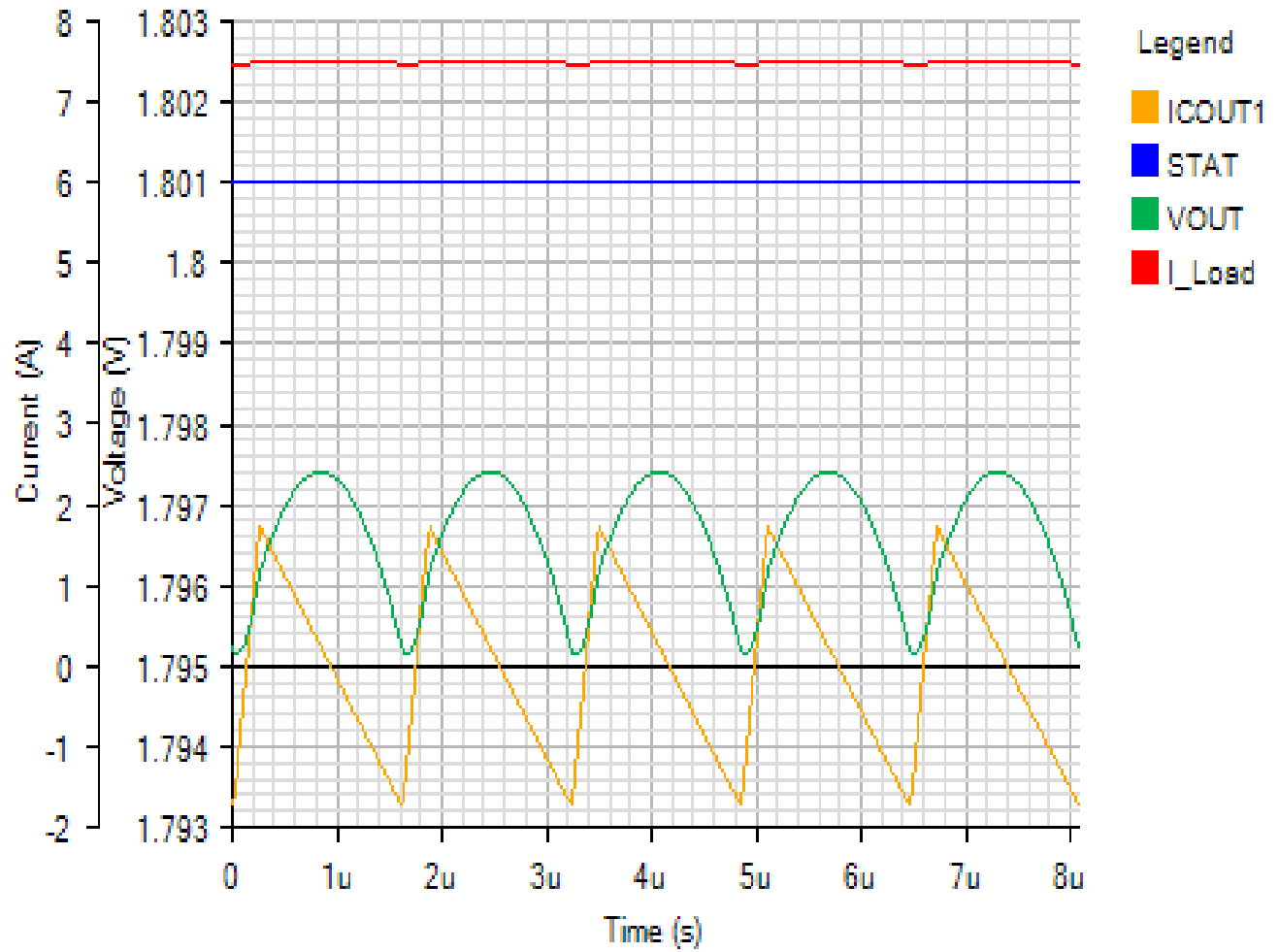


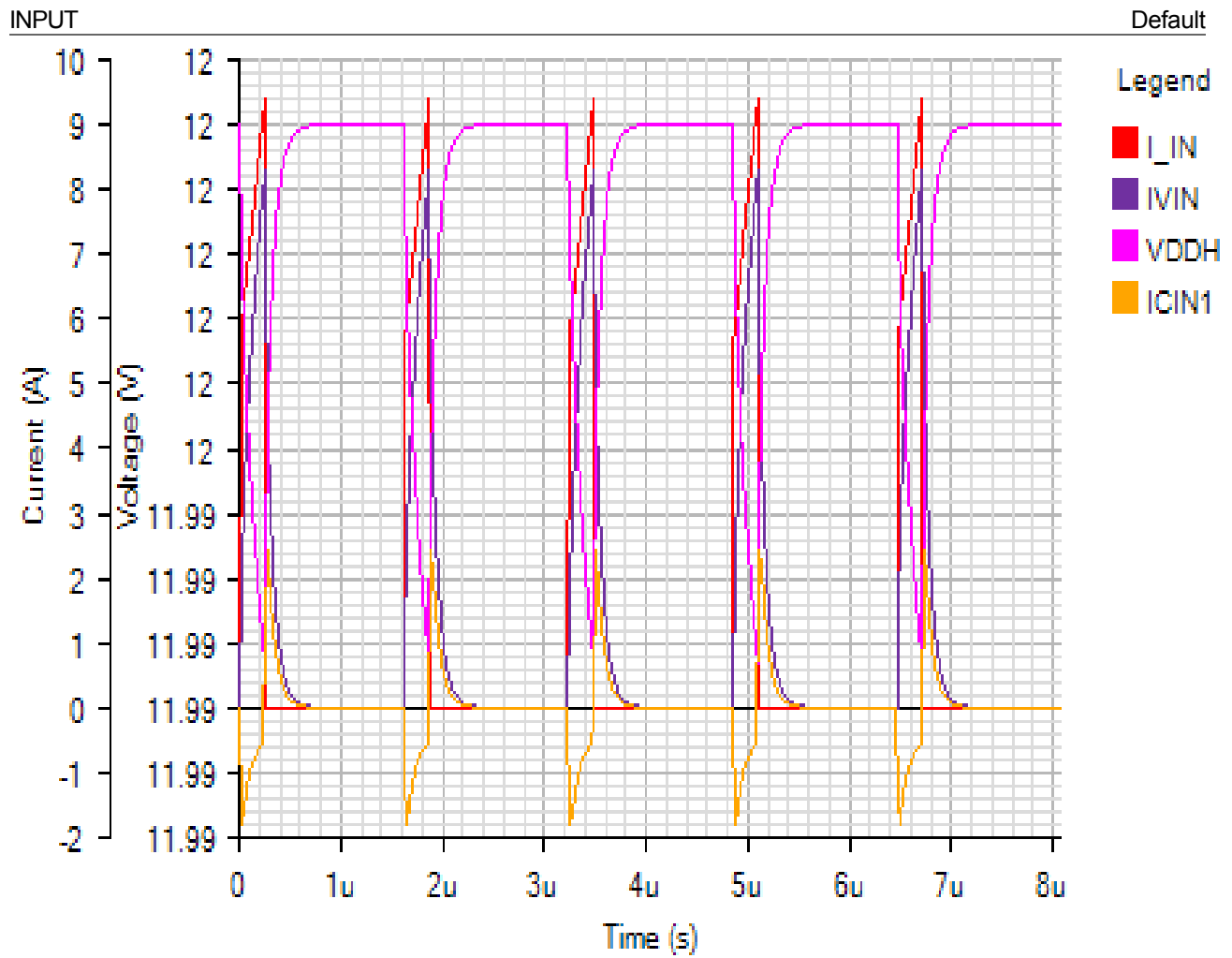
Steady State - Tue Nov 20 2018 13:54:57



OUTPUT

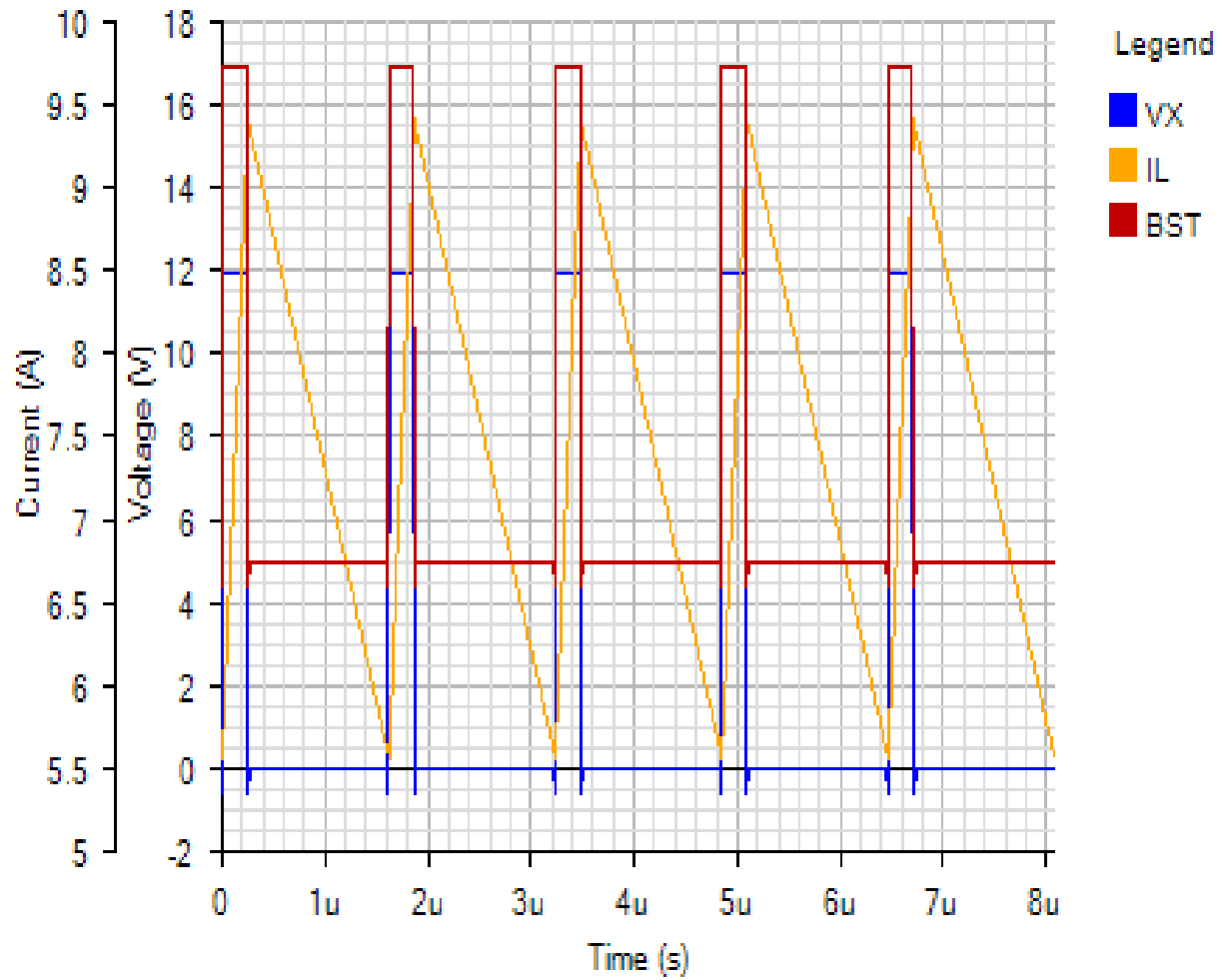
Default





SWITCHING

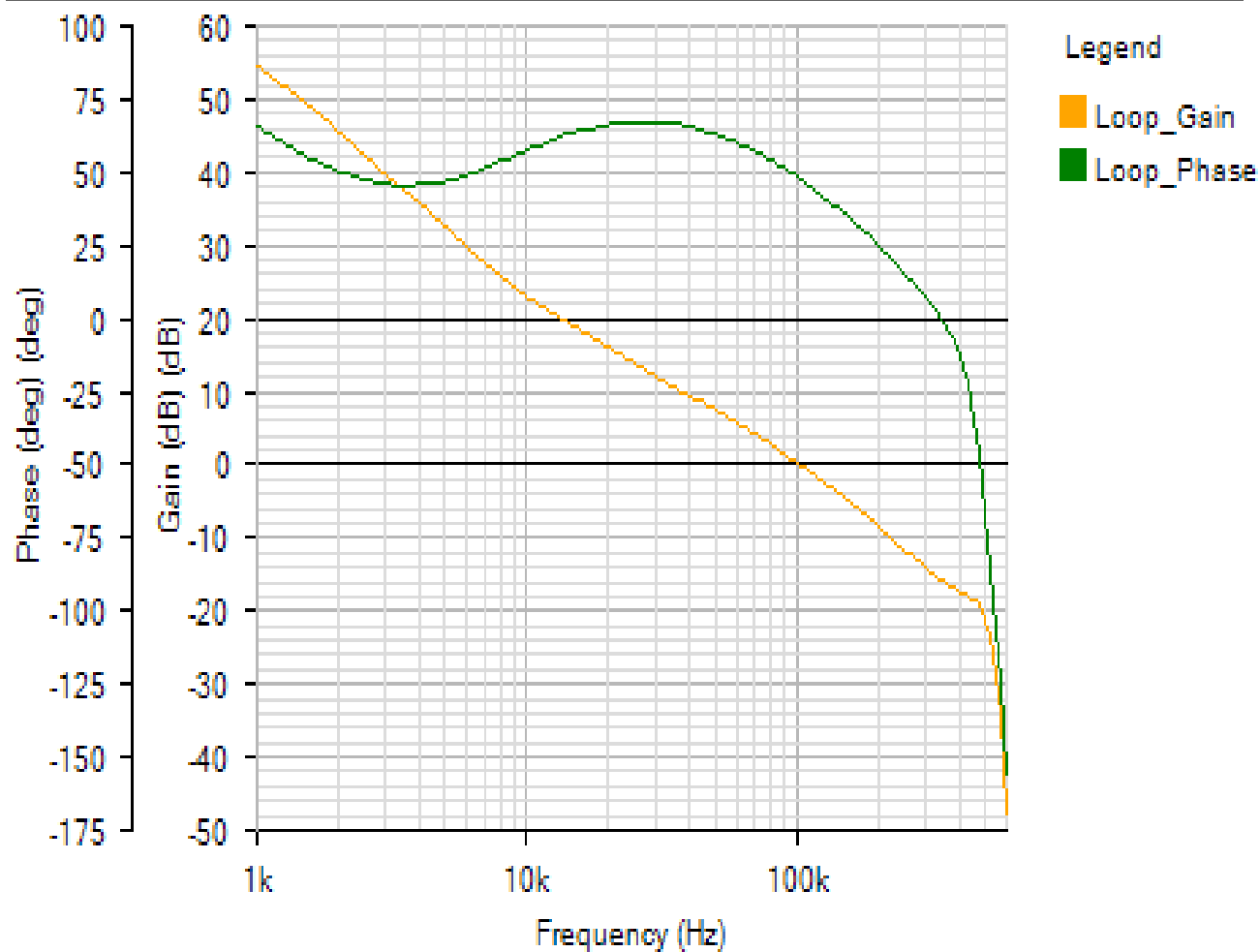
Default



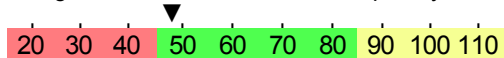
AC Loop - Tue Nov 20 2018 13:54:57

BODE

Default



Phase Margin: 47.74° at a crossover frequency of 102.5kHz



The diagram shows two signals: VCC (red) and OE (blue). The VCC signal is a square wave that transitions from high to low at approximately 500ns and back to high at approximately 1.5ms. The OE signal is a square wave that transitions from high to low at approximately 500ns and back to high at approximately 1.5ms. The signals are synchronized, with OE transitioning at the same time as VCC.

OUTPUT

Default

